## ALUMINUM ELECTROLYTIC CAPACITORS

## nichicon



Chip Type, High Reliability High Temperature (260°C) Reflow







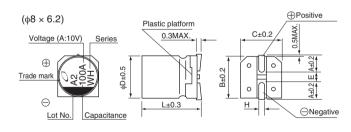
 Corresponding with 260°C peak reflow soldering Recomended reflow condition : 260°C peak 5 sec. 230°C over 60 sec. 2 times (φ8 × 6.2, φ10 × 10 : 1 time)

- Chip type high temperature range, for +125°C use.
- Applicable to automatic mounting machine fed with carrier tape.
- Compliant to the RoHS directive (2011/65/EU).
- AEC-Q200 compliant. Please contact us for details.

#### Specifications

Item	Performance Characteristics										
Category Temperature Range	-40 to +125°C										
Rated Voltage Range	10 to 50V										
Rated Capacitance Range	10 to 330µF										
Capacitance Tolerance	±20% at 120Hz, 20°C										
Leakage Current	After 1 minute's app	After 1 minute's application of rated voltage at 20°C, leakage current is not more than 0.03CV or 4(µA), whichever is greater.									
				Measur	emen	it frequ	ency : 12	0Hz at 20	°C		
Tangent of loss angle (tan $\delta$ )	Rated voltage (V)										
	tan δ (MAX.)	0.32	0.24	0.21		0.1	8	0.18			
	Measurement frequency : 120Hz										
Stability at Low Temperature	Rated voltage (V)		10	16	2	25	35	50			
Stability at Low Temperature	Impedance ratio ZT / Z20 (MAX.)	Z–40°C / Z+20°C	C 12	8	(	6	4	4			
Endurance	the capacitors are re	the capacitors are restored to 20°C after the rated $\frac{1}{\tan \delta}$ 300% or						±30% of the initial capacitance value or less than the initial specified value han or equal to the initial specified value			
Shelf Life	After storing the capacitors under no load at 125°C for 1000 hours and then performing voltage treatment based on JIS C 5101-4 clause 4.1 at 20°C, they shall meet the specified values for the endurance characteristics listed above.										
Resistance to soldering heat	requirements listed at right when they are removed from the plate					tan δ Less than or equal t		Within ±10% of the initial capacitanc Less than or equal to the initial specifie Less than or equal to the initial specifie	d value		
Marking	Black print on the ca	ase top.									

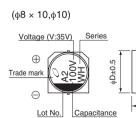
### Chip Type

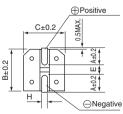


Plastic platform

0.3MAX

L±0.5

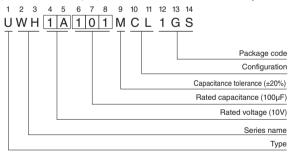




#### Voltage

0					
V	10	16	25	35	50
Code	Α	С	E	V	Н

## Type numbering system (Example : 10V $100 \mu F)$



			(mm)
φD×L	8×6.2	8×10	10 × 10
A	3.3	2.9	3.2
В	8.3	8.3	10.3
С	8.3	8.3	10.3
E	2.3	3.1	4.5
L	6.2	10	10
Н	0.5 to 0.8	0.8 to 1.1	0.8 to 1.1

# UWH

#### Dimensions

	V	1	0	1	6	2	5	3	5	50	)
Cap.(µF)	Code	1.	A	1	С	1	E	1\	V	11	4
10	100		1		1		1			8×6.2	24
22	220				1		1			8×6.2	38
33	330				 			8×6.2	44	8×10	46
47	470				1	8×6.2	48	8×10	52	10 × 10	58
100	101	8×6.2	58	8×10	66	8×10	74	10 × 10	80		
220	221	8×10	90	10 × 10	102	10 × 10	116			Case size	Rated
330	331	10 × 10	112		1		1			$\phi D \times L (mm)$	ripple

Rated ripple current (mArms) at 125°C 120Hz

• Frequency coefficient of rated ripple current

Frequency	50 Hz	120 Hz	300 Hz	1 kHz	10 kHz or more
Coefficient	0.70	1.00	1.17	1.36	1.50

• Taping specifications are given in page 23.

• Recommended land size, soldering by reflow are given in page 18, 19.

• Please refer to page 3 for the minimum order quantity.